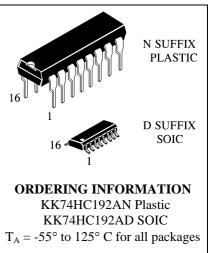
## **KK74HC192A**

## Presettable BCD/Decade UP/DOWN Counter High-Performance Silicon-Gate CMOS

The KK74HC192A is identical in pinout to the LS/ALS192. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LS/ALSTTL outputs.

The counter has two separate clock inputs, a Count Up Clock and Count Down Clock inputs. The direction of counting is determined by which input is clocked. The outputs change state synchronous with the LOW-to-HIGH transitions on the clock inputs. This counter may be preset by entering the desired data on the P0, P1, P2, P3 input. When the Parallel Load input is taken low the data is loaded independently of either clock input. This feature allows the counters to be used as devide-by-n by modifying the count lenght with the preset inputs. In addition the counter can also be cleared. This is accomplished by inputting a high on the Master Reset input. All 4 internal stages are set to low independently of either clock input.Both a Terminal Count Down (TC<sub>D</sub>) and Terminal Count Up (TC<sub>U</sub>) Outputs are provided to enable cascading of both up and down counting functions. The TC<sub>D</sub> output produces a negative going pulse when the counter underflows and TC<sub>II</sub> outputs a pulse when the counter overflows. The counter can be cascaded by connecting the  $TC_{U}$ and TC<sub>D</sub> outputs of one device to the Count Up Clock and Count Down Clock inputs, respectively, of the next device.

- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μA
- High Noise Immunity Characteristic of CMOS Devices



#### **PIN ASSIGNMENT**

Р1 [	1•	16	v <sub>cc</sub>
Q <sub>1</sub> [	2	15	P <sub>0</sub>
Q <sub>0</sub> [	3	14	MR
CPD	4	13	$\overline{\text{TC}}_{\text{D}}$
ср <sub>U</sub> [	5	12	$\overline{\mathrm{TC}}_{\mathrm{U}}$
$Q_2$ [	6	11	PL
Q <sub>3</sub> [	7	10	P <sub>2</sub>
GND	8	9	P <sub>3</sub>

### Parallel Data Inputs Asynchronous Parallel Load ,PL $\stackrel{11}{=}$ $\stackrel{12}{=}$ TC D, Terminal Count Down $P_2 \stackrel{10}{=}$ $\stackrel{12}{=}$ TC U, Terminal Count Up $7 \stackrel{2}{=} Q_3$ $6 \stackrel{2}{=} Q_2$ $2 \stackrel{2}{=} Q_1$ $3 \stackrel{2}{=} Q_0$ Outputs Count UP Clock ,CP $\stackrel{5}{=}$ Count Down Clock,CP $\stackrel{4}{=}$ Asynchronous Master Reset ,MR $\stackrel{14}{=}$

LOGIC DIAGRAM

PIN 16 = $V_{CC}$ PIN 8 = GND



#### MAXIMUM RATINGS<sup>\*</sup>

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)	-1.5 to V <sub>CC</sub> +1.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND)	-0.5 to V <sub>CC</sub> +0.5	V
I <sub>IN</sub>	DC Input Current, per Pin	±20	mA
I <sub>OUT</sub>	DC Output Current, per Pin	±25	mA
I <sub>CC</sub>	DC Supply Current, $V_{CC}$ and GND Pins	±50	mA
P <sub>D</sub>	Power Dissipation in Still Air, Plastic DIP+ SOIC Package+	750 500	mW
Tstg	Storage Temperature	-65 to +150	°C
T <sub>L</sub>	Lead Temperature, 1 mm from Case for 10 Seconds (Plastic DIP or SOIC Package)	260	°C

<sup>\*</sup>Maximum Ratings are those values beyond which damage to the device may occur. Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: : - 7 mW/°C from 65° to 125°C

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)		6.0	V
$V_{IN}, V_{OUT}$	DC Input Voltage, Output Voltage (Referenced to GND)	0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types	-55	+125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Figure 1) $V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$	0 0 0	1000 500 400	ns

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{IN}$  and  $V_{OUT}$  should be constrained to the range  $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

			V <sub>CC</sub>	Guar	anteed L	imit	
Symbol	Parameter	Test Conditions	V	25 °C to -55°C	≤85 °C	≤125 °C	Unit
V <sub>IH</sub>	Minimum High- Level Input Voltage	$\begin{array}{l} V_{OUT}{=}0.1 \text{ V or } V_{CC}{-}0.1 \text{ V} \\ \mid I_{OUT} \mid \leq 20 \ \mu\text{A} \end{array}$	2.0 4.5 6.0	1.5 3.15 4.2	1.5 3.15 4.2	1.5 3.15 4.2	V
V <sub>IL</sub>	Maximum Low - Level Input Voltage	$V_{OUT}$ =0.1 V or V <sub>CC</sub> -0.1 V $ I_{OUT}  \le 20 \ \mu A$	2.0 4.5 6.0	0.3 0.9 1.2	0.3 0.9 1.2	0.3 0.9 1.2	V
V <sub>OH</sub>	Minimum High- Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ \mid I_{OUT} \mid \leq 20 \ \mu A \end{array} $	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ \left  \begin{array}{c} I_{OUT} \right  &\leq 4.0 \text{ mA} \\ \left  \begin{array}{c} I_{OUT} \right  &\leq 5.2 \text{ mA} \end{array} \end{array} $	4.5 6.0	3.98 5.48	3.84 5.34	3.7 5.2	
V <sub>OL</sub>	Maximum Low- Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ \mid I_{OUT} \mid \leq 20 \ \mu A \end{array} $	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$ \begin{array}{l} V_{IN} = V_{IH} \text{ or } V_{IL} \\ \left  \begin{array}{c} I_{OUT} \right  &\leq 4.0 \text{ mA} \\ \left  \begin{array}{c} I_{OUT} \right  &\leq 5.2 \text{ mA} \end{array} \end{array} $	4.5 6.0	0.26 0.26	0.33 0.33	0.4 0.4	
I <sub>IN</sub>	Maximum Input Leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0	±0.1	±1.0	±1.0	μΑ
I <sub>CC</sub>	Maximum Quiescent Supply Current (per Package)	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>OUT</sub> =0µA	6.0	8.0	80	160	μΑ

### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

#### **FUNCTION TABLE**

	I	nputs	Mode	
MR	PL	CP <sub>U</sub>	CPD	
Н	Х	Х	Х	Reset(Asyn.)
L	L	Х	Х	Preset(Asyn.)
L	Н	$\left  \right\rangle$	Н	No Count
L	Н		Н	Count Up
L	Н	Н	$\langle \rangle$	Count Down
L	Н	Н	7	No Count

X = don't care

The IN74HC192 can be preset to any state, but will not count beyond 9. If preset to state 10, 11, 12, 13, 14 or 15, it will follow the sequence 10, 11, 6: 12, 13, 4: 14, 15, 2 if counting Up, and follow the sequence 15, 14, 13, 12, 11, 10, 9 if counting Down.

sequence 15, 14, 13, 12, 11, 10, 9 if counting Down. Logic equations For Terminal Count:

 $\frac{\text{TC}_{\text{U}} = Q_0 \bullet Q_3 \bullet \text{CP}_{\text{U}}}{\text{TC}_{\text{D}} = Q_0 \bullet Q_1 \bullet Q_2 \bullet Q_3 \bullet \text{CP}_{\text{D}}}$ 

		$V_{CC}$	Gua	aranteed L	imit	
Symbol	Parameter	V	25 °C to -55°C	≤85°C	≤125°C	Unit
$\mathbf{f}_{\max}$	Minimum Clock Frequency (50% Duty Cycle) (Figures 1 and 6)	2.0 4.5 6.0	12 36 43	3.2 16 19	2.6 13 15	MHz
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Clock to Q (Figures 1 and 6)	2.0 4.5 6.0	215 43 37	270 54 46	325 65 55	ns
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, PL to Q (Figures 3 and 6)	2.0 4.5 6.0	215 43 37	270 54 46	325 65 55	ns
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Clock to Terminal Count (Figures 2 and 6)	2.0 4.5 6.0	125 25 21	155 31 26	190 38 32	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figures 1 and 6)	2.0 4.5 6.0	75 15 13	95 20 18	110 23 20	ns
C <sub>IN</sub>	Maximum Input Capacitance	-	10	10	10	pF

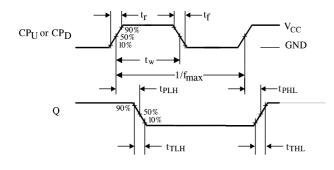
## AC ELECTRICAL CHARACTERISTICS ( $C_L$ =50pF,Input $t_r$ =t\_f=6.0 ns)

	Power Dissipation Capacitance (Per Package)	Typical @25°C,V <sub>CC</sub> =5.0 V	
C <sub>PD</sub>	Used to determine the no-load dynamic power consumption: $P_D=C_{PD}V_{CC}^2f+I_{CC}V_{CC}$	60	pF

### **TIMING REQUIREMENTS** (C<sub>L</sub>=50pF,Input t<sub>r</sub>=t<sub>f</sub>=6.0 ns)

		V <sub>CC</sub>	Guaranteed Limit			
Symbol	Parameter	V	25 °C to -55°C	≤85°C	≤125°C	Unit
t <sub>su</sub>	Minimum Setup Time, Pn to PL (Figure 4)	2.0 4.5 6.0	100 20 18	125 35 22	150 30 26	ns
t <sub>h</sub>	Minimum Hold Time, Pn to PL (Figure 4)	2.0 4.5 6.0	0 0 0	0 0 0	0 0 0	ns
t <sub>w</sub>	Minimum Pulse Width, Clock (Figure 1)	2.0 4.5 6.0	150 30 26	190 38 33	225 45 38	ns
t <sub>w</sub>	Minimum Pulse Width, PL (Figure 3)	2.0 4.5 6.0	100 20 17	125 25 26	150 30 26	ns
t <sub>w</sub>	Minimum Pulse Width, MR (Figure 5)	2.0 4.5 6.0	100 20 17	125 25 26	150 30 26	ns
t <sub>r</sub> , t <sub>f</sub>	Minimum Input Rise and Fall Times (Figure 1)	2.0 4.5 6.0	100 500 400	100 500 400	100 500 400	ns





 $\frac{CP_U \text{ or } CP_D}{TC_U \text{ or } TC_D} \xrightarrow{t_{PHL}} 50\%$ 

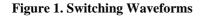


Figure 2. Switching Waveforms

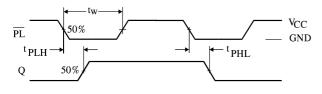
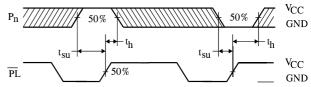
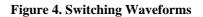
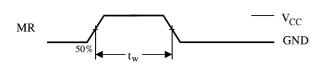
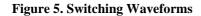


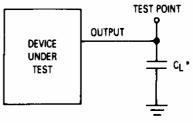
Figure 3. Switching Waveforms





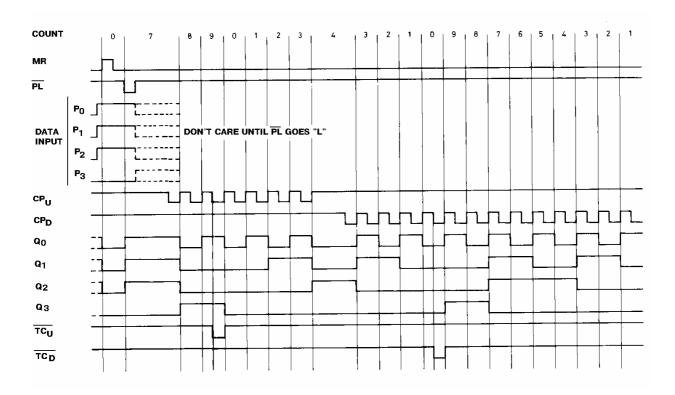






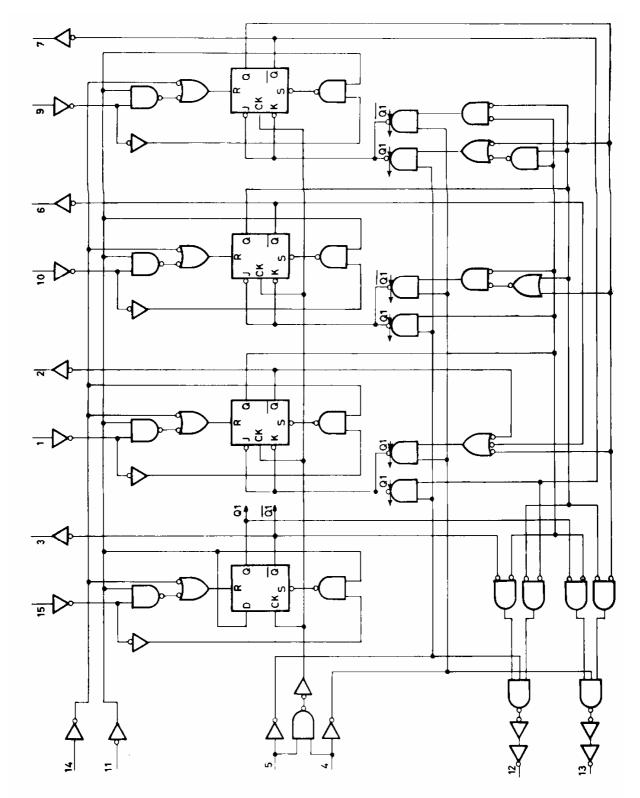
\*Includes all probe and jig capacitance.

**Figure 6. Test Circuit** 



### TIMING DIAGRAM





# EXPANDED LOGIC DIAGRAM

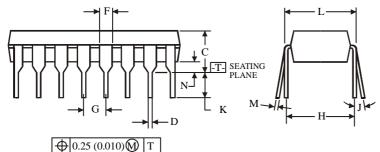




#### N SUFFIX PLASTIC DIP (MS - 001BB)

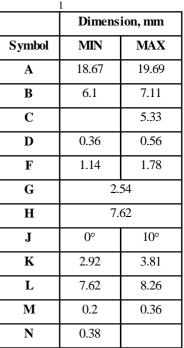


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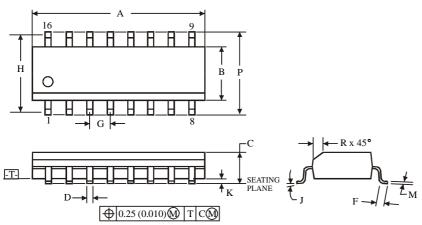




 Dimensions "A", "B" do not include mold flash or protrusions. Maximum mold flash or protrusions 0.25 mm (0.010) per side.



D SUFFIX SOIC (MS - 012AC)



#### NOTES:

- 1. Dimensions A and B do not include mold flash or protrusion.
- 2. Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B 0.25 mm (0.010) per side.



	Dimension, mm			
Symbol	MIN	MAX		
Α	9.8	10		
В	3.8	4		
С	1.35	1.75		
D	0.33	0.51		
F	0.4	1.27		
G	1.	27		
Н	5.	72		
J	0°	8°		
K	0.1	0.25		
М	0.19	0.25		
Р	5.8	6.2		
R	0.25	0.5		